

## Diode Modules

## PSKD 312

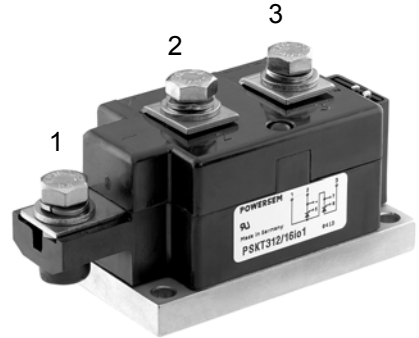
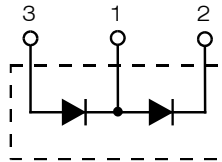
$$I_{FRMS} = 2 \times 520 \text{ A}$$

$$I_{FAVM} = 2 \times 310 \text{ A}$$

$$V_{RRM} = 1200-2200 \text{ V}$$

Preliminary Data Sheet

$V_{RSM}$ V	$V_{RRM}$ V	Type
1300	1200	PSKD 312/12
1500	1400	PSKD 312/14
1700	1600	PSKD 312/16
1900	1800	PSKD 312/18
2100	2000	PSKD 312/20
2300	2200	PSKD 312/22



Symbol	Test Conditions	Maximum Ratings
$I_{FRMS}$ $I_{FAVM}$	$T_{VJ} = T_{VJM}$ $T_C = 100^\circ\text{C}; 180^\circ \text{ sine}$	520 A 310 A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C};$ $V_R = 0$	$t = 10 \text{ ms (50 Hz)}$ 10500 A
		$t = 8.3 \text{ ms (60 Hz)}$ 11200 A
$ji^2dt$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz)}$ 551000 A <sup>2</sup> s
		$t = 8.3 \text{ ms (60 Hz)}$ 527000 A <sup>2</sup> s
$T_{VJ}$ $T_{VJM}$ $T_{stg}$	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms (50 Hz)}$ 9200 A
		$t = 8.3 \text{ ms (60 Hz)}$ 9800 A
$V_{ISOL}$	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$ 3000 V~
		$t = 1 \text{ s}$ 3600 V~
$M_d$	Mounting torque (M6) Terminal connection torque (M8)	4.5-7/40-62 Nm/lb.in.
		11-13/97-115 Nm/lb.in.
Weight	Typical including screws	750 g

Symbol	Test Conditions	Characteristic Values
$I_{RRM}$	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	30 mA
$V_F$	$I_F = 600 \text{ A}; T_{VJ} = 25^\circ\text{C}$	1.32 V
$V_{T0}$ $r_T$	For power-loss calculations only $T_{VJ} = T_{VJM}$	0.8 V 0.6 mΩ
$R_{thJC}$	per diode; DC current per module	0.12 K/W
		0.06 K/W
$R_{thJK}$	per diode; DC current per module	0.16 K/W
		0.08 K/W
$Q_S$	$T_{VJ} = 125^\circ\text{C}; I_F = 400 \text{ A}; -di/dt = 50 \text{ A}/\mu\text{s}$	700 μC
$I_{RM}$		260 A
$d_S$	Creeping distance on surface	12.7 mm
$d_A$	Creepage distance in air	9.6 mm
$a$	Maximum allowable acceleration	50 m/s <sup>2</sup>

### Features

- Direct copper bonded Al<sub>2</sub>O<sub>3</sub>-ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 148688

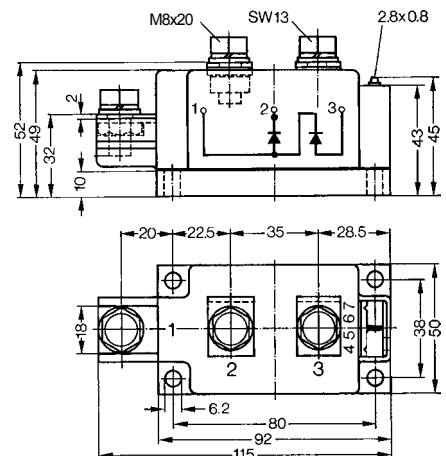
### Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

### Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

### Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.

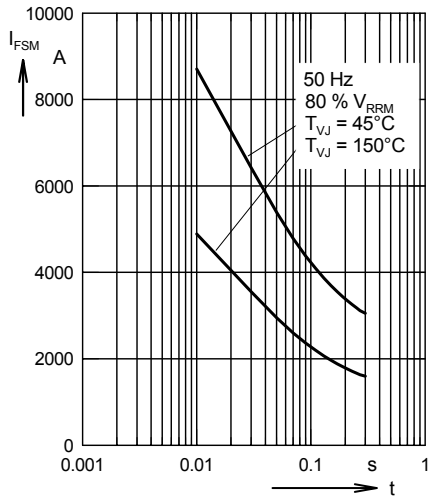


Fig. 1 Surge overload current  
 $I_{FSM}$ : Crest value,  $t$ : duration

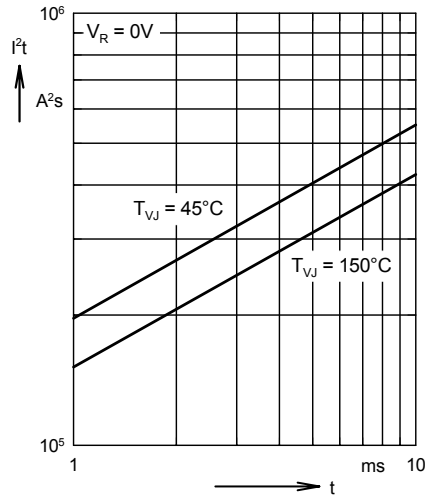


Fig. 2  $I^2t$  versus time (1-10 ms)

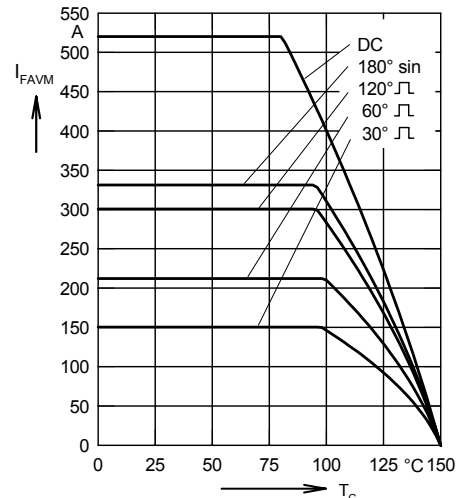


Fig. 3 Maximum forward current at case temperature

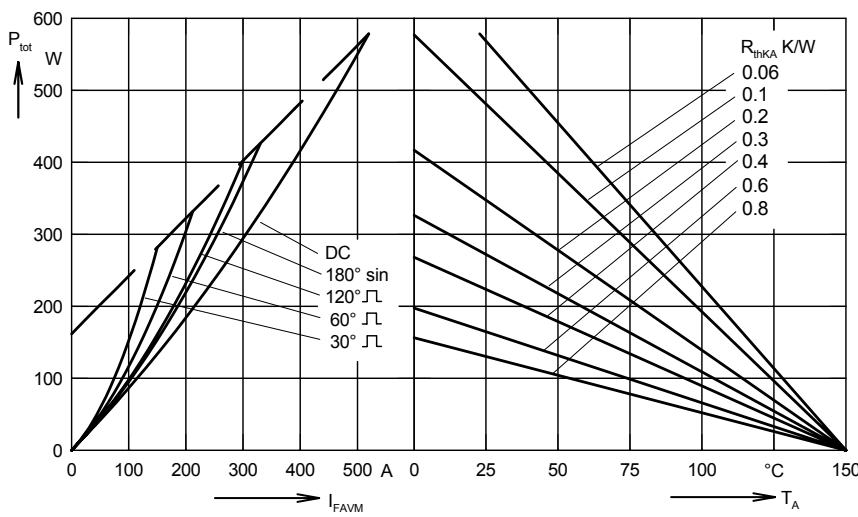


Fig. 4 Power dissipation versus forward current and ambient temperature (per diode)

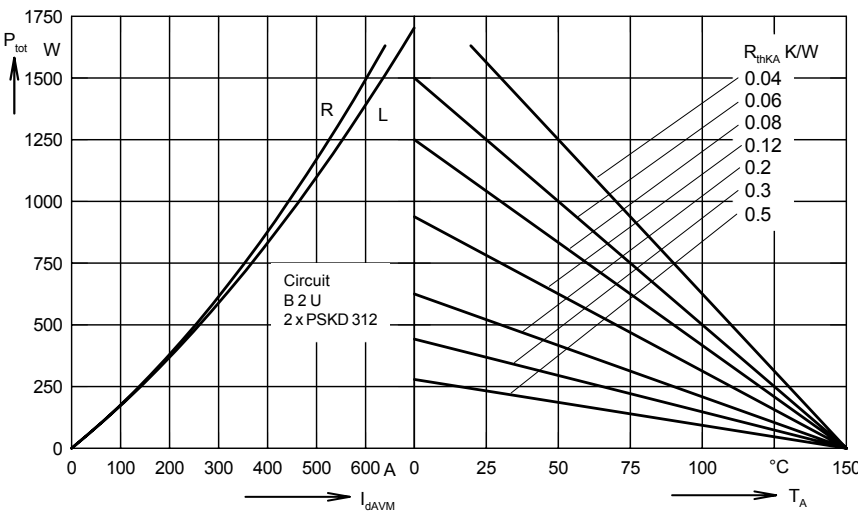


Fig. 5 Single phase rectifier bridge:  
 Power dissipation versus direct output current and ambient temperature  
 R = resistive load  
 L = inductive load

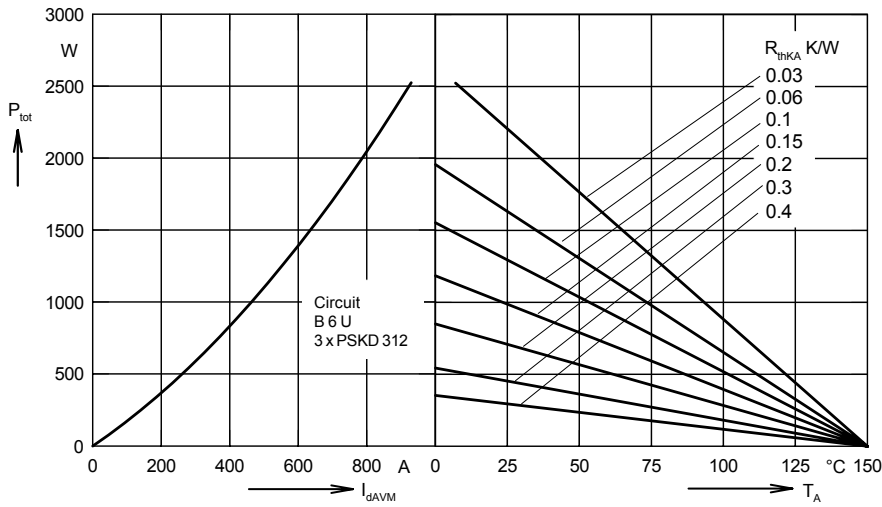


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

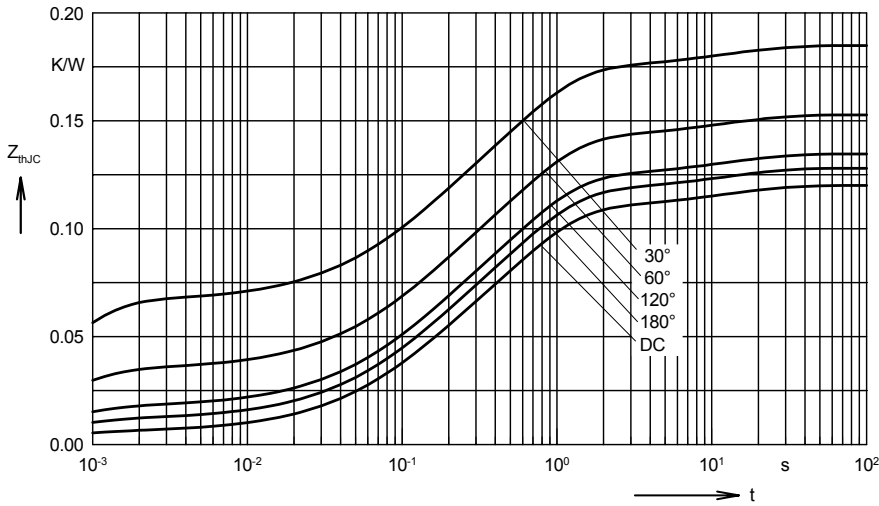


Fig. 7 Transient thermal impedance junction to case (per diode)

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ (K/W)
DC	0.120
180°C	0.128
120°C	0.135
60°C	0.153
30°C	0.185

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0058	0.00054
2	0.031	0.098
3	0.072	0.54
4	0.0112	12

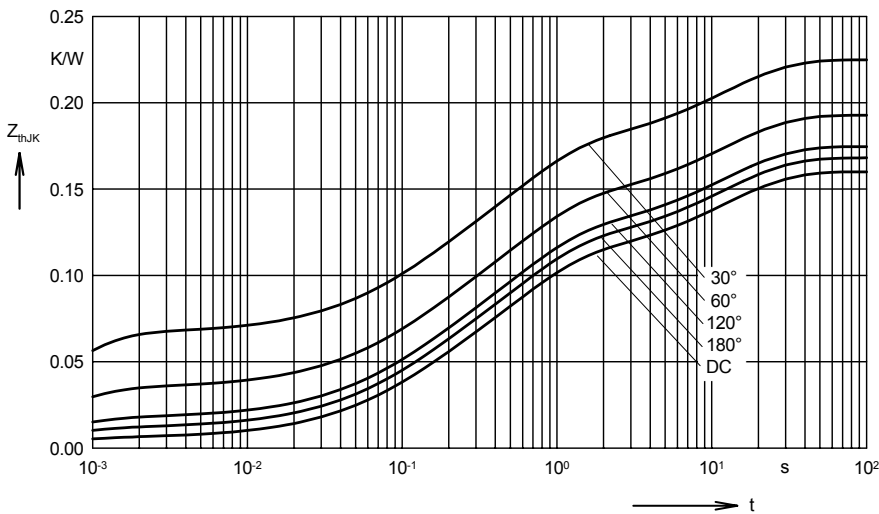


Fig. 9 Transient thermal impedance junction to heatsink (per diode)

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ (K/W)
DC	0.160
180°C	0.168
120°C	0.175
60°C	0.193
30°C	0.225

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.0058	0.00054
2	0.031	0.098
3	0.072	0.54
4	0.0112	12
5	0.04	12